

SILICON POWER TRANSISTOR 2SD1588

NPN SILICON EPITAXIAL TRANSISTOR FOR LOW-FREQUENCY POWER AMPLIFIERS AND LOW-SPEED SWITCHING

FEATURES

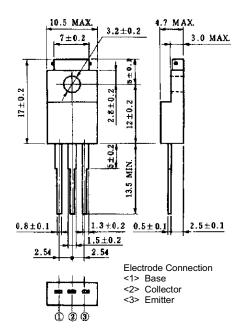
- Mold package that does not require an insulating board or insulation bushing
- Large current capacity in small dimension: Ic(DC) = 7 A
- Low collector saturation voltage: VcE(sat) = 0.5 V MAX. (@5 A)
- Ideal for use in ramp drivers or inductance drivers
- Complementary transistor: 2SB1097

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	VcBo	100	V
Collector to emitter voltage	Vceo	60	V
Emitter to base voltage	V _{EBO}	7.0	V
Collector current (DC)	Ic(DC)	7.0	Α
Collector current (Pulse)	I _{C(pulse)} *	15	Α
Base current (DC)	I _{B(DC)}	3.5	Α
Total power dissipation	P _T (T _C = 25°C)	30	W
Total power dissipation	P _T (T _A = 25°C)	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

^{*} PW \leq 300 μ s, duty cycle \leq 10%

PACKAGE DRAWING (UNIT: mm)



ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = 80 \text{ V}, I_{E} = 0$			10	μΑ
Emitter cutoff current	ІЕВО	$V_{EB} = 5.0 \text{ V}, \text{ Ic} = 0$			10	μΑ
DC current gain	hFE1**	Vce = 1.0 V, Ic = 3 A	40		200	
DC current gain	hFE2**	Vce = 1.0 V, Ic = 5 A	20			
Collector saturation voltage	V _{CE(sat)} **	Ic = 5 A, Iв = 0.5 A			0.5	٧
Base saturation voltage	V _{BE(sat)} **	Ic = 5 A, I _B = 0.5 A			1.5	V

^{**} Pulse test PW \leq 350 μ s, duty cycle \leq 2%/per pulsed

hfe CLASSIFICATION

Marking	М	L	К
h _{FE1}	40 to 80	60 to 120	100 to 200

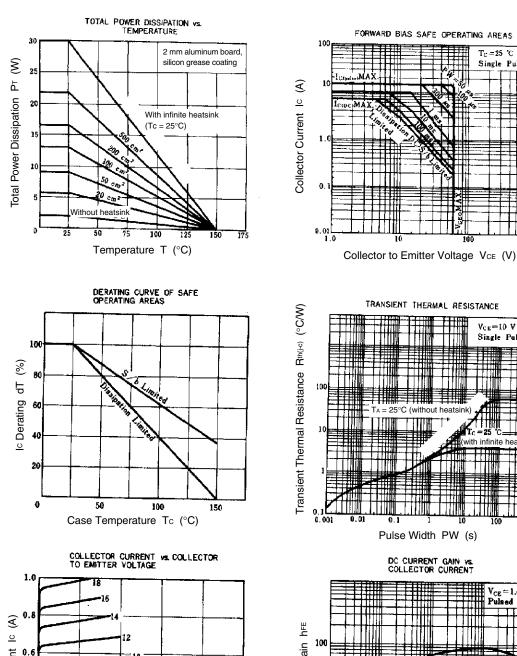
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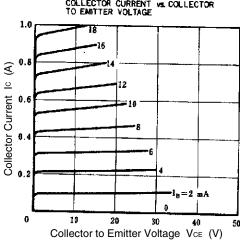
T_C = 25 °C

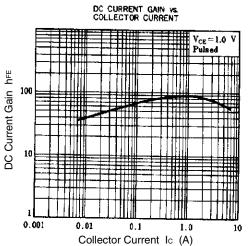
Single Pulse

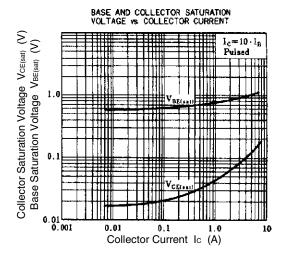


TYPICAL CHARACTERISTICS (TA = 25°C)









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